

RJL5032DPP-M0

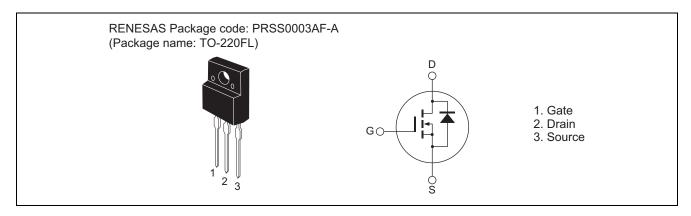
Silicon N Channel MOS FET High Speed Power Switching

R07DS0251EJ0100 Rev.1.00 May 23, 2011

Features

- Low on-state resistance $R_{DS(on)}=2.2~\Omega~typ.~(at~I_D=1.5~A,~V_{GS}=10~V,~Ta=25^{\circ}C)$
- High speed switching
- Built in fast recovery diode

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Value	Unit
Drain to source voltage	V_{DSS}	500	V
Gate to source voltage	V_{GSS}	±30	V
Drain current	I _D	3	А
Drain peak current	I _D (pulse) Note1	12	А
Avalanche current	I _{AP} Note3	3	А
Channel dissipation	Pch Note 2	30.6	W
Channel to case thermal Impedance	θch-c	4.08	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. Pulse width limited by safe operating area.

- 2. Value at Tc = 25°C
- 3. STch = 25° C, Tch $\leq 150^{\circ}$ C

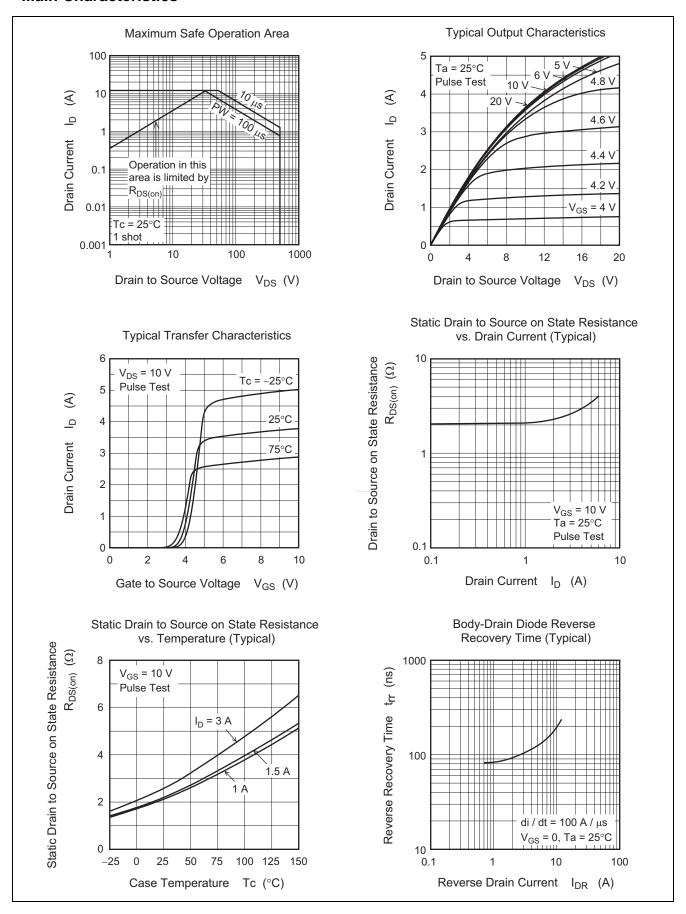
Electrical Characteristics

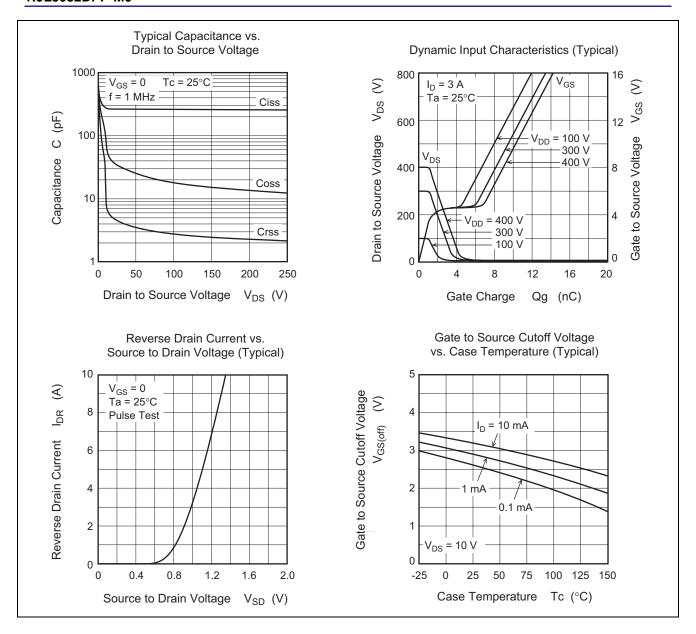
 $(Ta = 25^{\circ}C)$

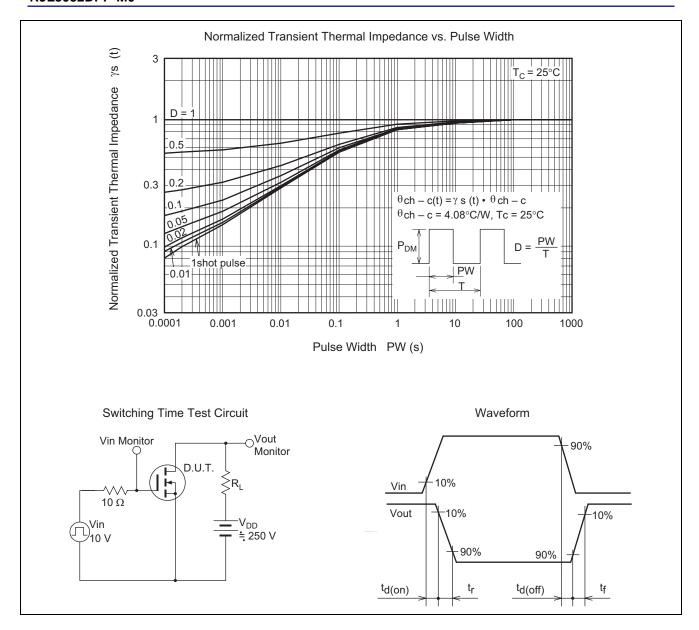
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	500	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	10	μΑ	$V_{DS} = 500 \text{ V}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	_	±0.1	μΑ	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$
Gate to source cutoff voltage	V _{GS (off)}	2	_	4	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Static drain to source on state resistance	R _{DS (on)}	_	2.2	2.8	Ω	$I_D = 1.5 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note 4}}$
Input capacitance	Ciss	_	265	_	рF	V _{DS} = 25 V
Output capacitance	Coss	_	35	_	рF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	4.5	_	рF	f = 1 MHz
Turn-on delay time	t _{d (on)}	_	6	_	ns	V _{DD} = 250 V
Rise time	t _r	_	2.5	_	ns	I _D = 1.5 A
Turn-off delay time	t _{d (off)}	_	20	_	ns	V _{GS} = 10 V
Fall time	t _f	_	25	_	ns	$Rg = 10 \Omega$
Total gage charge	Qg	_	10.3	_	nC	V _{DD} = 400 V
Gate to source charge	Qgs	_	1.5	_	nC	V _{GS} = 10 V
Gate to drain charge	Qgd	_	5.2	_	nC	$I_D = 3 A$
Body-drain diode forward voltage	V_{DF}	_	0.9	1.5	V	$I_F = 3 \text{ A}, V_{GS} = 0^{\text{Note 4}}$
Body-drain diode reverse recovery time	t _{rr}	_	100	_	ns	$I_F = 3 A, V_{GS} = 0$
						V _{DD} = 250 V
						di _F /dt = 100 A/μs

Note: 4. Pulse test

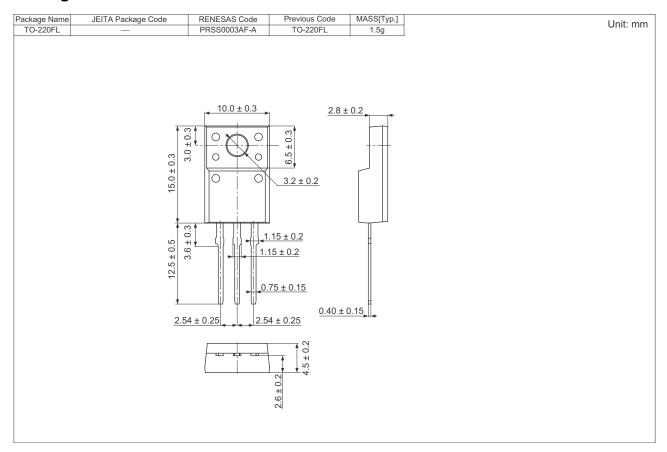
Main Characteristics







Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJL5032DPP-M0-T2	600 pcs	Box (Tube)

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